PRELIMINARY DATA SHEET



GaAs INTEGRATED CIRCUIT μ PG2121TB

L-BAND UP/DOWN CONVERTER

DESCRIPTION

The μ PG2121TB is L-band up-converter or down-converter IC (LO Buff. Amp. + Passive Mixer). The device can convert the RF frequency to IF frequency and operate low current. It housed in an original 6-pin super minimold package that is smaller than usual 6-pin minimold easy to install and contributes to miniaturizing the system.

FEATURES

- +2.8 V single voltage
- Low distortion (IIP3 = +23 dBm TYP.)
- Low current operation (IDD = 3.5 mA TYP.)
- · LO buffer amplifier and passive mixer on a single chip
- 6-pin super minimold package (Size: 2.0 × 1.25 × 0.9 mm)

APPLICATION

· L-band digital cellular etc.

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
μPG2121TB-E3	6-pin super minimold	G2E	Embossed tape 8 mm wide.
			Pin 1 face the tape perforation side.
			Qty 3kpcs / reel.

Remark To order evaluation samples, please contact your local NEC sales office. (Part number for sample order: μ PG2121TB)

Caution The IC must be handled with care to prevent static discharge because its circuit composed of GaAS HJ-FET.

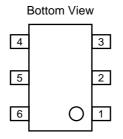
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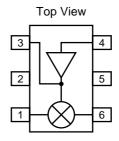
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

PIN CONNECTIONS

Pin No.	Connection	Pin No.	Connection
1	RF or IF	4	LO IN
2	GND	5	GND
3	V _{DD}	6	IF or RF







ABSOLUTE MAXIMUM RATINGS (TA = +25 °C)

Parameter	Symbol	Ratings	Unit
Supply Voltage	V _{DD}	6.0	V
LO Input Power	PLO	+10	dBm
RF Input Power	P _{RF}	+10	dBm
Total Power Dissipation	Ptot	140 ^{Note}	mW
Operating Ambient Temperature	TA	-30 to +90	°C
Storage Temperature	Tstg	−35 to +150	°C

Note Mounted on a $50 \times 50 \times 1.6$ mm double copper clad epoxy glass PWB, $T_A = +85$ °C



ELECTRICAL CHARACTERISTICS (TA = +25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	V _{DD}	+2.7	+2.8	+3.0	٧
RF Frequency	fref	810	1	960	MHz
IF Frequency	fıF	50	_	400	MHz
LO Input Power	PLO	-10	-5	0	dBm

ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, $T_A = +25$ °C, $V_{DD} = 2.8$ V, $f_{RF1} = 850$ MHz, $f_{RF2} = 850.1$ MHz, $P_{RF1} = P_{RF2} = -3$ dBm, $f_{LO} = 940$ MHz, $P_{LO} = -5$ dBm, $f_{IF} = 90$ MHz, $f_{IM3} = 90.1$ MHz)

Parameter	Symbol	Test Condition	MIN.	TYP.	MAX.	Unit
Total Current	IDD		-	3.5	4.5	mA
Conversion Loss	Lc		-	-6.0	-7.5	dB
3rd Order Distortion Input Intercept Point Note	IIP3		+18	+23	-	dBm
3rd Order Intermoduration Distortion	IMз		-	-52	-42	dBc
Local Leackage	LLO		-	-13	-11	dBm

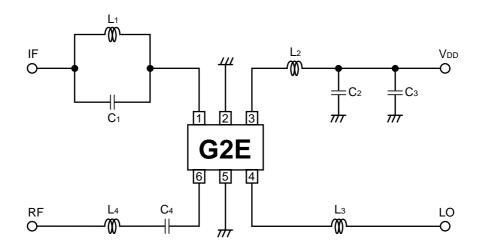
Note IIP3 is determined by comparing two method; theoretical calculation and cross point of IM3 curve.

IIP3 =
$$\frac{\Delta IM_3 \times P_{RF} + CG - P_{IM3}}{\Delta IM_3 - 1}$$
 [dBm] ΔIM_3 : P_{IM3} gradient

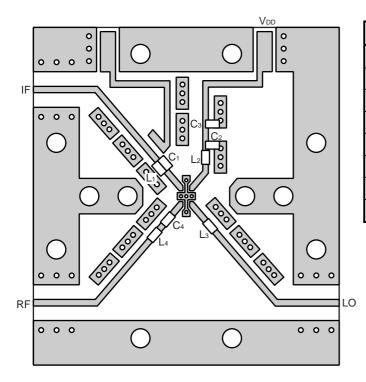
Calculated as $\Delta IM_3 = 3$

EVALUATION CIRCUIT

 $T_A = +25 \, ^{\circ}C$, $V_{DD} = +2.8 \, V$, $f = 850 \, MHz$



EVALUATION BOARD

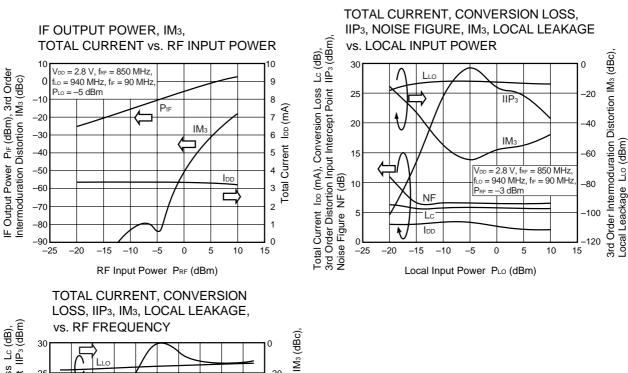


USING THE NEC EVALUATION BOARD

	Values	Part Number	Maker
C1	5 pF	GRM39CH 050 C50	muRata
C2	33 pF	GRM36CH 330 J50	muRata
Сз	1 000 pF	GRM39B 102 K50	muRata
C4	5 pF	GRM39CH 050 C50	muRata
L ₁	6.8 nH	TFL0510 6N8	susumu
L2	15 nH	TFL0816 15N	susumu
Lз	27 nH	TFL0816 27N	susumu
L4	6.8 nH	TFL0816 6N8	susumu



TYPICAL CHARACTERISTICS (Unless otherwise specified, TA = +25 °C)

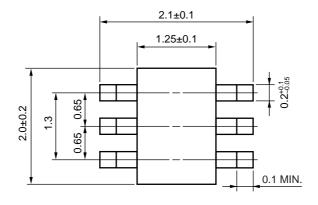


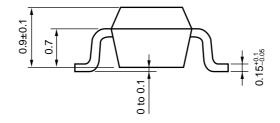
Total Current $\,$ lop (mA), Conversion Loss $\,$ Lc (dB), 3rd Order Distortio Input Intercept Point $\,$ IIP3 (dBm) $\,$ Intermoduration Distortion IM3 (dBc) 25 ♥ 2.8 V, fLO = 895 to 985 MHz IIP: $f_{RF1} = 850 \text{ MHz}, f_{RF2} = 850.1 \text{ MHz}, f_{IF} = 90 \text{ MHz}, P_{RF} = -3 \text{ dBm},$ 20 <u>-5 dBm</u> _ocal Leackage LLo (dBm) IMa 15 10 3rd Order 800 810 820 830 840 850 860 870 880 890 900 RF Frequency fRF (MHz)

Remark The graphs indicate nominal characteristics.

PACKAGE DIMENSIONS

6-PIN SUPER MINIMOLD (UNIT: mm)







RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235 °C or below Time: 30 seconds or less (at 210 °C) Count: 3, Exposure limit: None ^{Note}	IR35-00-3
VPS	Package peak temperature: 215 °C or below Time: 40 seconds or less (at 200 °C) Count: 3, Exposure limit: None ^{Note}	VP15-00-3
Wave Soldering	Soldering bath temperature: 260 °C or below Time: 10 seconds or less Count: 1, Exposure limit: None ^{Note}	WS60-00-1
Partial Heating	Pin temperature: 300 °C Time: 3 seconds or less (per side of device) Exposure limit: None ^{Note}	_

Note After opening the dry pack, keep it in a place below 25 °C and 65 % RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

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CAUTION

The great care must be taken in dealing with the devices in this guide.

The reason is that the material of the devices is GaAs (Gallium Arsenide), which is designated as harmful substance according to the law concerned.

Keep the law concerned and so on, especially in case of removal.

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